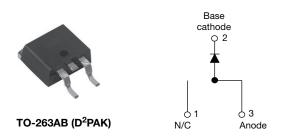
Vishay Semiconductors

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High Performance Schottky Rectifier, 7.5 A



PRODUCT SUMMARY							
Package TO-263AB (D ² PAK)							
I _{F(AV)}	7.5 V						
V _R	35 V, 45 V						
V _F at I _F	0.57						
I _{RM} max.	15 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	7.0 mJ						

FEATURES

- 150 °C T_J operation
- · High frequency operation
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201, class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBRB7... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES U								
I _{F(AV)}	Rectangular waveform	7.5	A					
V _{RRM}		35, 45	V					
I _{FSM}	t _p = 5 μs sine	690	A					
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V					
TJ	Range	-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRB735PbF	VS-MBRB745PbF	UNITS				
Maximum DC reverse voltage	V _R	35	45	V				
Maximum working peak reverse voltage	V _{RWM}	55	45	v				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T_{C} = 131 °C, rated V_{R}	7.5					
Non-repetitive peak surge current	I _{FSM}	5 µs sine	Following any rated load condition and with rated V _{RRM} applied	690	А			
	-	Surge applied at rated load c	150					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 3.5	7	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to Frequency limited by T_J max	2	А				

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Document Number: 94312

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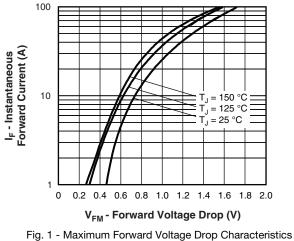
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST	VALUES	UNITS				
		15 A	T _J = 25 °C	0.84	V			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	7.5 A	T = 125 °C	0.57				
		15 A	T _J = 125 °C	0.72				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Dated DC valtage	0.1	0			
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	15	mA			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal	400	pF				
Typical series inductance	L _S	Measured from top of	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

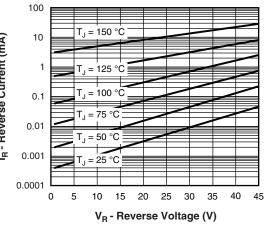
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperat	ure range	TJ		-65 to +150	°C			
Maximum storage temperate	ure range	T _{Stg}		-65 to +175	C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	3.0	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approvimate weight				2	g			
Approximate weight				0.07	oz.			
Maunties terrere				6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device			Case style D2DAK	MBR	B735			
			Case style D ² PAK	MBR	B745			

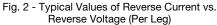
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(Per Leg)

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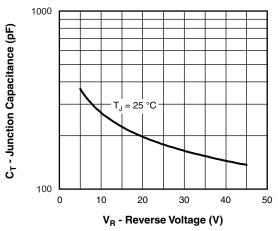


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

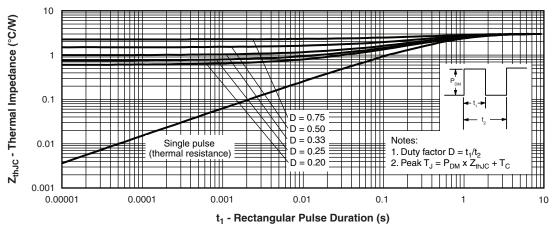
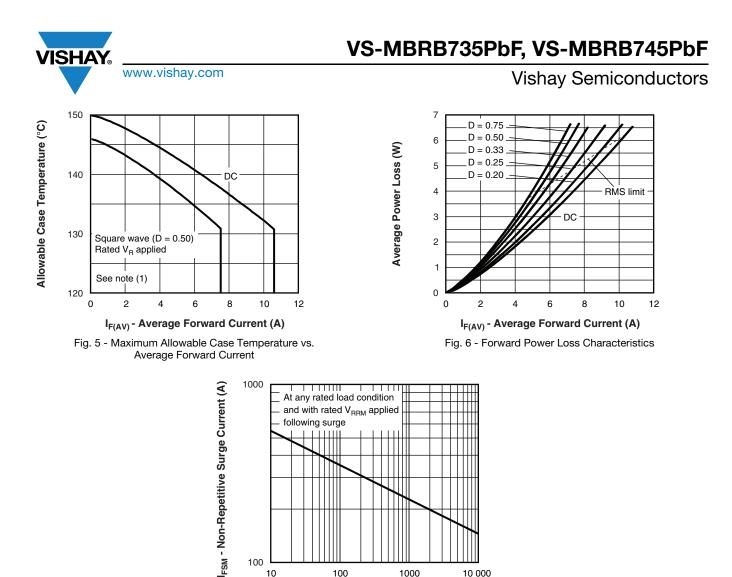


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

 $T_{J} = 150 °C$ $T_{J} = 150 °C$ $T_{J} = 125 °C$ $T_{J} = 25 °C$ $T_{J} = 25 °C$ 0.01 $T_{J} = 125 °C$ 0.01 $T_{J} = 125 °C$ 0.01 $T_{J} = 125 °C$ 0.01

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = rated V_R$

100

10

100

t_p - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

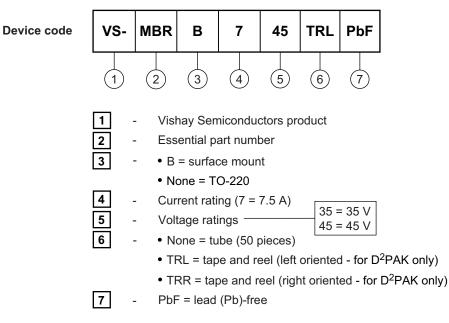
10 000

1000



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Dimensions www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95298					

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

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SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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